

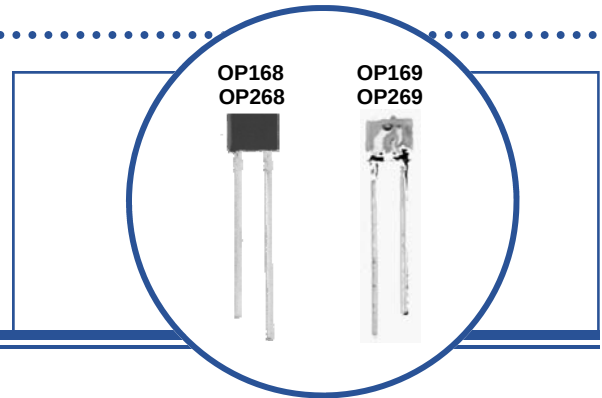
Plastic Infrared Emitting Diode

OP168F, OP169, OP268F, OP269 Series



Features:

- Flat lens for wide radiation angle (OP168, OP268)
- Integral lens for narrow beam angle (OP169, OP269)
- Easily stackable on 0.100" (2.54 mm) hole centers
- Mechanically and spectrally matched to other OPTEK devices



Description:

Each diode in this series is molded into an end-looking plastic package. The package for all **OP168F** and **OP268F** devices is black, whereas the package for all **OP169** and **OP269** packages is clear. **OP168F** and **OP169** devices are GaAs. **OP268F** and **OP269** devices are GaAlAs.

The **OP268FPS** is an 850nm gallium aluminum arsenide infrared emitting diode molded in a end-looking miniature plastic package. The advantage of this emitter is that it emits photons from a 0.004" area that is aligned with the package optical centerline. Unlike other GaAlAs emitters, this device performs more like an ideal point source and is suitable for use with lenses to create collimated light sources that can be used in a variety of applications.

Due to their small size, all diodes in this series offer considerable design flexibility.

The OP168F and OP268F series are mechanically and spectrally matched to the OP508F series phototransistor and the OP538F series photodarlington. The OP169 and OP269 series are mechanically and spectrally matched to the OP509 series phototransistors.

Please refer to Application Bulletins 208 and 210 for additional design information and reliability (degradation) data.

For custom screening contact your OPTEK representative.

Applications:

- Space-limited applications
- Excellent design flexibility
- PCBoard mounted slotted switch
- PCBoard interrupter

Ordering Information			
Part Number	LED Peak Wavelength	Total Beam Angle	Lead Length
OP168FA	935 nm	104°	0.50"
OP168FB			
OP168FC			
OP169A	935 nm	18°	
OP169B			
OP169C			
OP268FA	890 nm	104°	
OP268FB			
OP268FC			
OP268FPS	850 nm	50°	
OP269A	890 nm	18°	
OP269B			
OP269C			



RoHS

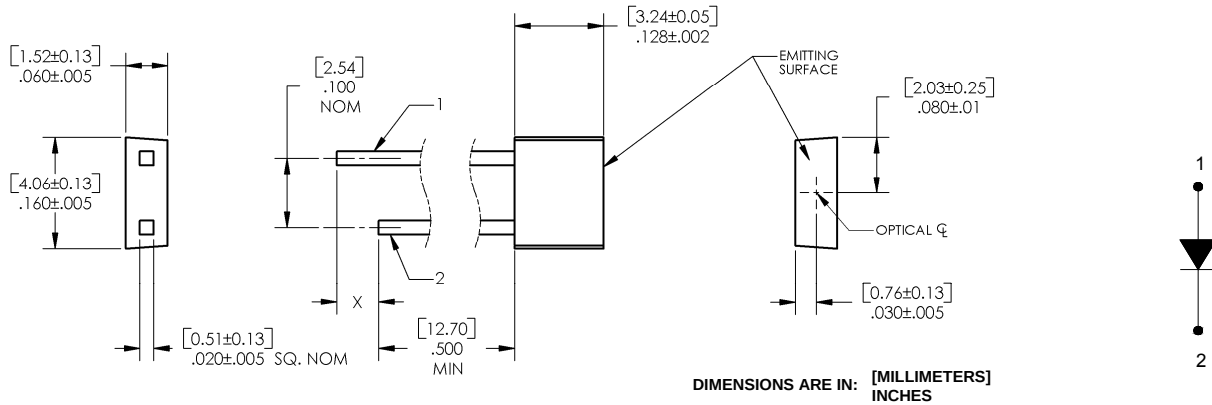
OPTEK reserves the right to make changes at any time in order to improve design and to supply the best product possible.

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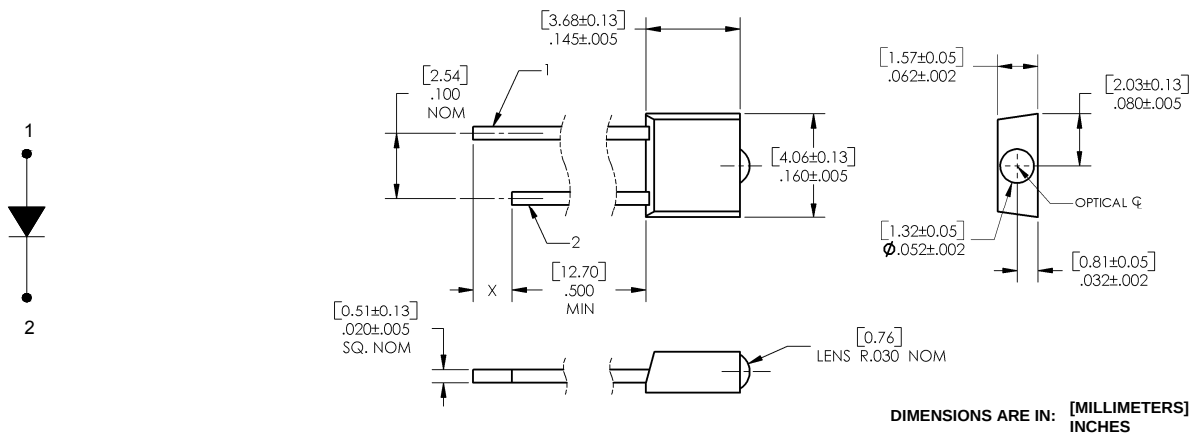


OP168F (A, B, C), OP268F (A, B, C, PS)



Pin #	LED X=0.060" (1.5 mm)
1	Anode
2	Cathode

OP169 (A, B, C), OP269 (A, B, C)



Pin #	LED X=0.060" (1.5 mm)
1	Anode
2	Cathode

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Plastic Infrared Emitting Diode

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Absolute Maximum Ratings ($T_A=25^{\circ}\text{C}$ unless otherwise noted)

Storage and Operating Temperature Range	-40° C to +100° C
Reverse Voltage	2.0 V
Continuous Forward Current	50 mA
Peak Forward Current (1 μs pulse width, 300 pps) OP168, OP169, OP268, OP269 (A, B, C) OP268FPS	3.0 A 100 mA
Lead Soldering Temperature [1/16 inch (1.6 mm) from case for 5 seconds with soldering iron] ⁽¹⁾	260° C
Power Dissipation ⁽²⁾	100 mW

Electrical Characteristics ($T_A = 25^{\circ}\text{C}$ unless otherwise noted)

SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS
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Input Diode

$E_{E(APT)}^{(3)}$	Apertured Radiant Incidence					
	OP168FA	0.48	-	-		
	OP168FB	0.43	-	0.73		
	OP168FC	0.27	-	-		
	OP169A	0.18	-	-		
	OP169B	0.11	-	0.22		
	OP169C	0.03	-	-		
	OP268FA	0.64	-	-		
	OP268FB	0.45	-	0.99		
	OP268FC	0.36	-	-		
	OP268FPS	0.10	-	0.90		
	OP269A	0.58	-	-		
	OP269B	0.42	-	0.82		
	OP269C	0.34	-	-		
V_F	Forward Voltage					
	OP168, OP169	-	-	1.40	V	$I_F = 20\text{ mA}$
	OP268, OP269	-	-	1.50		
	OP268FPS	-	-	1.80		
I_R	Reverse Current					
	OP168, OP169, OP268, OP269 OP268FPS	-	-	100 20	μA	$V_R = 2.0\text{ V}$
λ_P	Wavelength at Peak Emission					
	OP168, OP169	-	935	-		
	OP268, OP269	-	890	-		
	OP268FPS	-	850	-	nm	$I_F = 20\text{ mA}$

Notes:

1. RMA flux is recommended. Duration can be extended to 10 seconds maximum when flow soldering. A maximum of 20 grams force may be applied to the leads when soldering.
2. Derate linearly 1.33 mW/° C above 25° C.
3. For OP168 (FA, FB, FC) and OP268 (FA, FB, FC), $E_{E(APT)}$ is a measurement of the average apertured radiant energy incident upon a sensing area 0.081" (2.06 mm) in diameter perpendicular to and centered on the mechanical axis of the lens and 0.400" (10.16 mm) from the measurement surface. For OP169 (A, B, C) and OP269 (A, B, C), $E_{E(APT)}$ is a measurement of the average apertured radiant energy incident upon a sensing area 0.180" (4.57 mm) in diameter perpendicular to and centered on the mechanical axis of the lens and 0.653" (16.6 mm) from the lens tip. NOTE: $E_{E(APT)}$ is a measurement of the average radiant intensity within the cone formed by the above conditions. $E_{E(APT)}$ is not necessarily uniform within the measured area.

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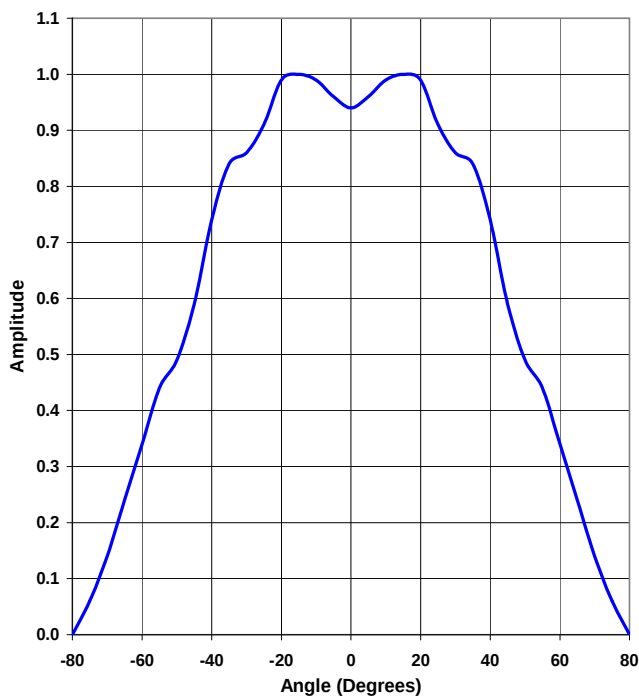
Electrical Characteristics ($T_A = 25^\circ\text{C}$ unless otherwise noted — for reference only)

SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS
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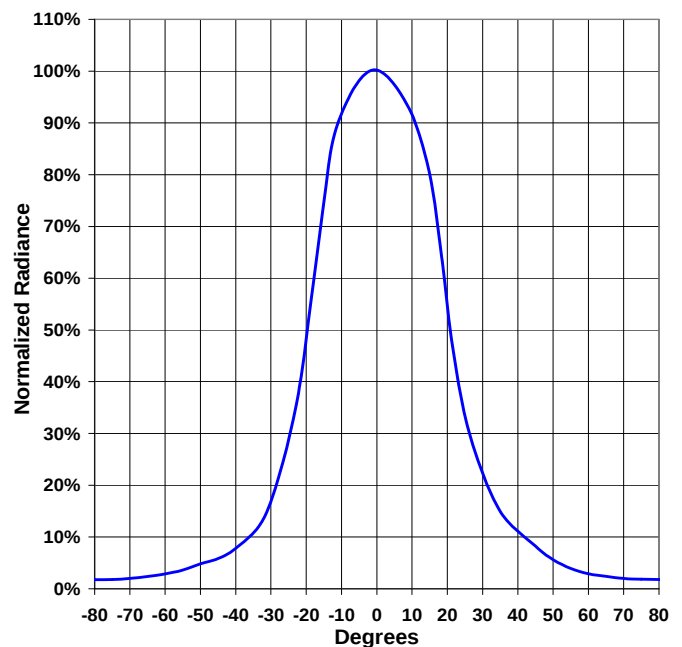
Input Diode

B	Spectral Bandwidth between Half Power Points OP168, OP169, OP268FPS OP268, OP269	- -	50 80	- -	nm	$I_F = 10 \text{ mA}$
$\Delta\lambda_p / \Delta T$	Spectral Shift with Temperature OP168, OP169, OP268, OP269	- -	± 0.30 ± 0.18	- -	nm/ $^\circ\text{C}$	$I_F = \text{Constant}$
θ_{HP}	Emission Angle at Half Power Points OP168 OP169 OP268 OP268FPS OP269	- - - - -	104° 46° 104° 50° 46°	- - - - -	Degree	$I_F = 20 \text{ mA}$
t_r	Rise Time OP168, OP169 OP268, OP269 OP268FPS	- - -	1000 500 10	- - -	ns	$I_{F(PK)} = 100 \text{ mA}$, PW=10 μs , D.C.=10%
t_f	Fall Time OP168, OP169 OP268, OP269 OP268FPS	- - -	500 250 10	- - -	ns	$I_{F(PK)} = 100 \text{ mA}$, PW=10 μs , D.C.=10%

Beam Angle OP168 & OP268 Package

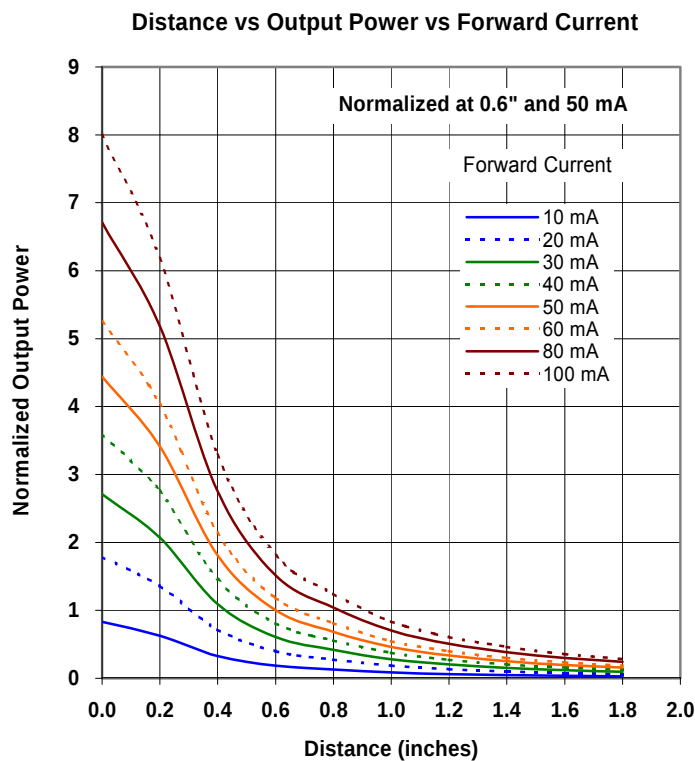
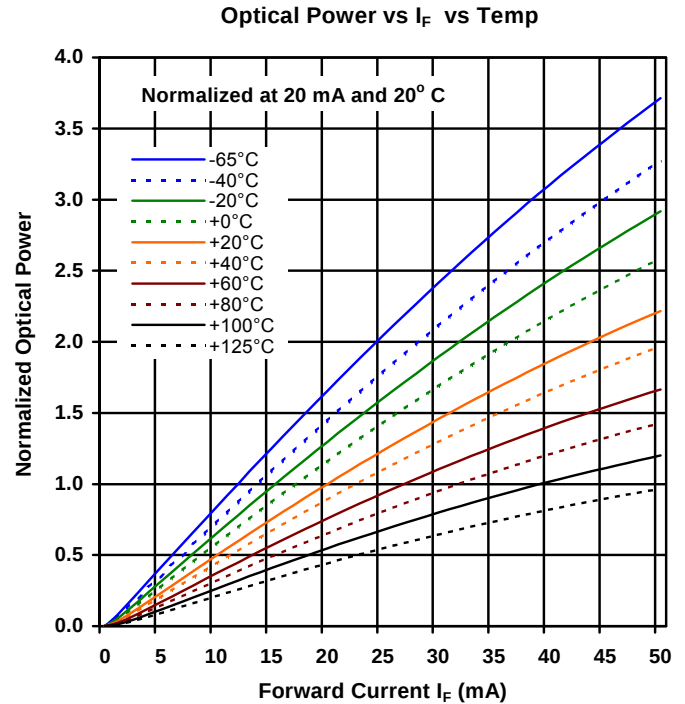
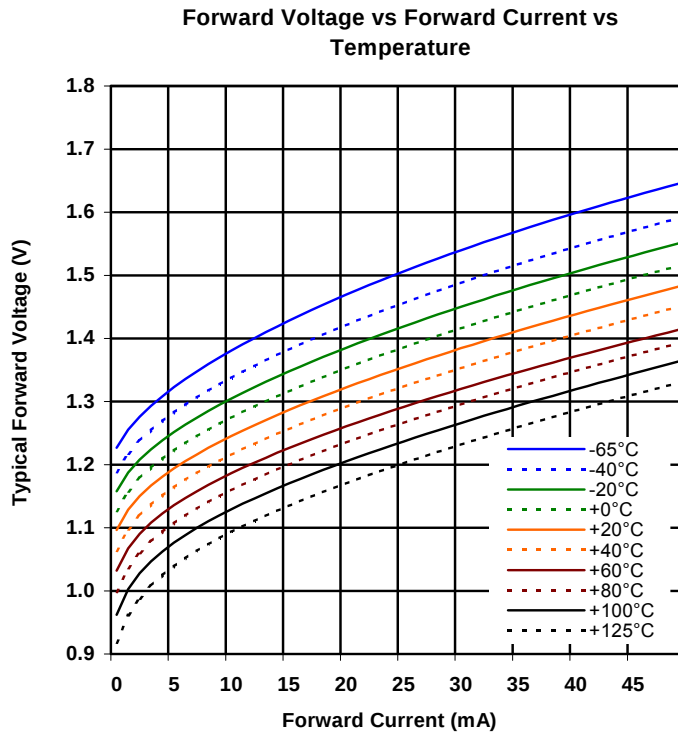


Beam Angle OP169 & OP269 Package



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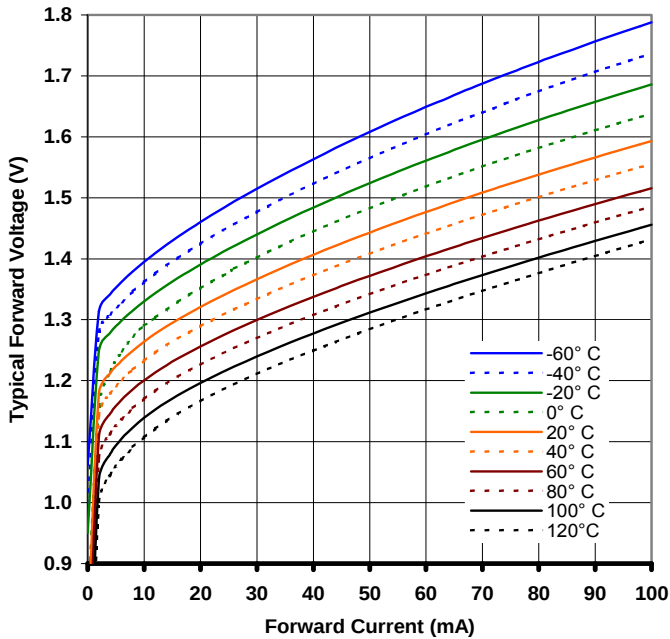
OP168 (FA, FB, FC), OP169 (A, B, C)



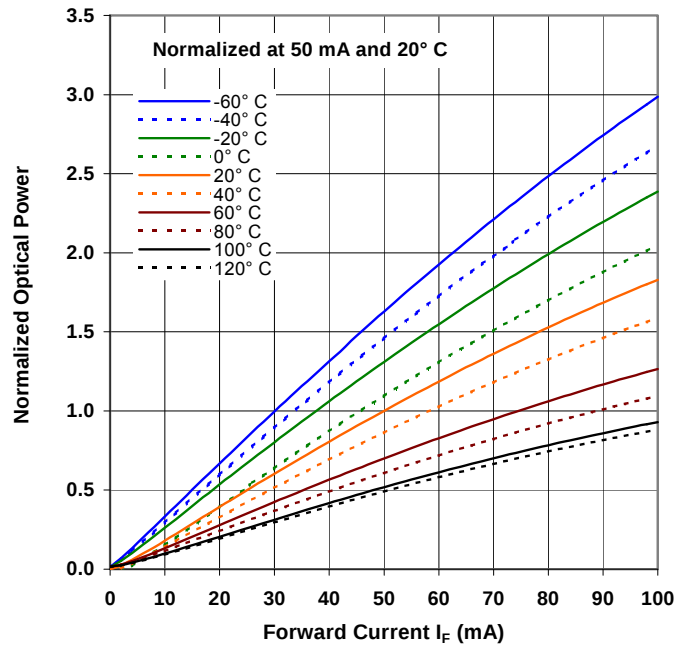
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OP268 (FA, FB, FC, FPS), OP269 (A, B, C)

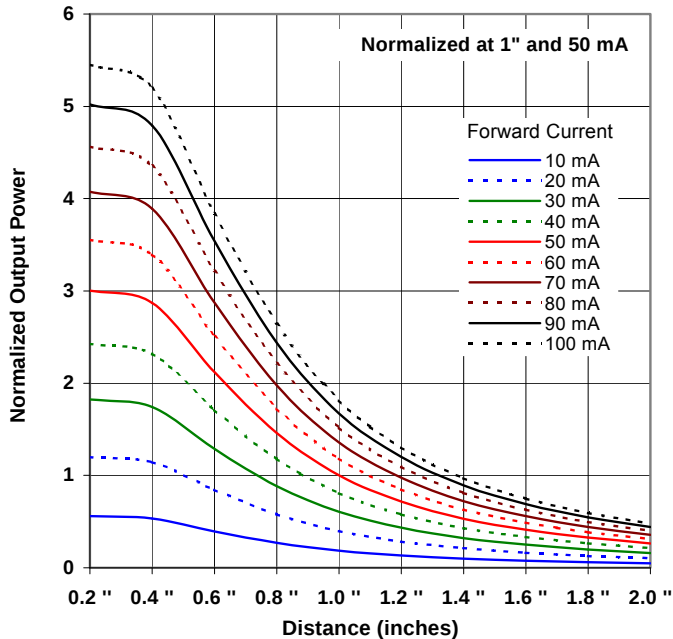
Forward Voltage vs Forward Current vs Temperature



Optical Power vs I_F vs Temperature



Distance vs Output Power vs Forward Current



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Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



Как с нами связаться

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